

SHOWA DENKO PHOTONICS CO., LTD.

Jul. 2022

BRH-35

Color Infrared
 Material AlGaAs/GaAs

3. Electrode N side (cathode): Au / P side (anode): Au

4. Electrode pattern (Fig.)

5. Chip size $0.325 \text{mm} \times 0.325 \text{mm} \times 0.280 \text{mmH}$ (Fig.)

6. Electro-Optical characteristics (Ta = 25°C)

Parameters	Symbol	Condition	Characteristics			l lmit
			Min.	Тур.	Max.	Unit
Power*	Ро	IF = 20mA	0.7	1.1		mW
Forward Voltage	VF	IF = 20mA		1.75	1.90	V
Reverse Current	lR	VR = 5V			10	μA
Peak Wavelength	λР	IF = 20mA		700		nm
Spectral Radiation Bandwidth	Δλ	IF = 20mA		20		nm

^{*} Power Measurement at SHOWA DENKO PHOTONICS.

LED chip: To be mounted on TO-18 gold header without resin coating.

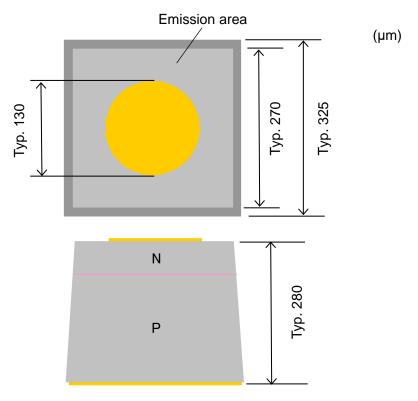


Fig. Electrode pattern & Chip size

The information contained herein is believed to be reliable.

However, no representations, guaranties or warranties of any kind are made as to accuracy and suitability of the Product for particular applications or the results of its use.

SHOWA DENKO PHOTONICS CO., LTD. reserves the right to introduce changes without notice.